
HOPE

High Density Power Electronics for FC- and
ICE-Hybrid Electric Vehicle Powertrains

FP6-019848

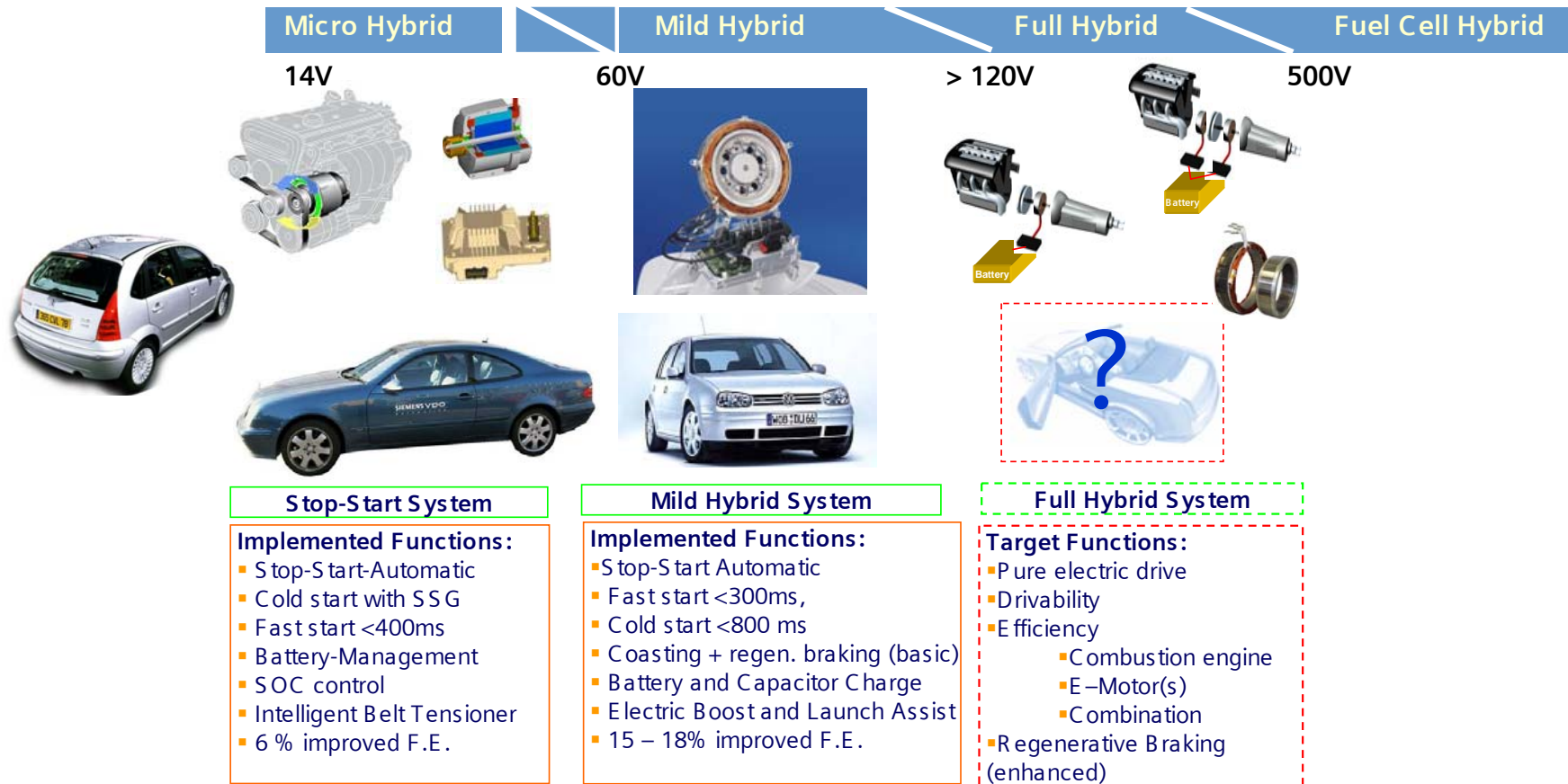
01/01/06 – 31/12/2008

Consortium Members

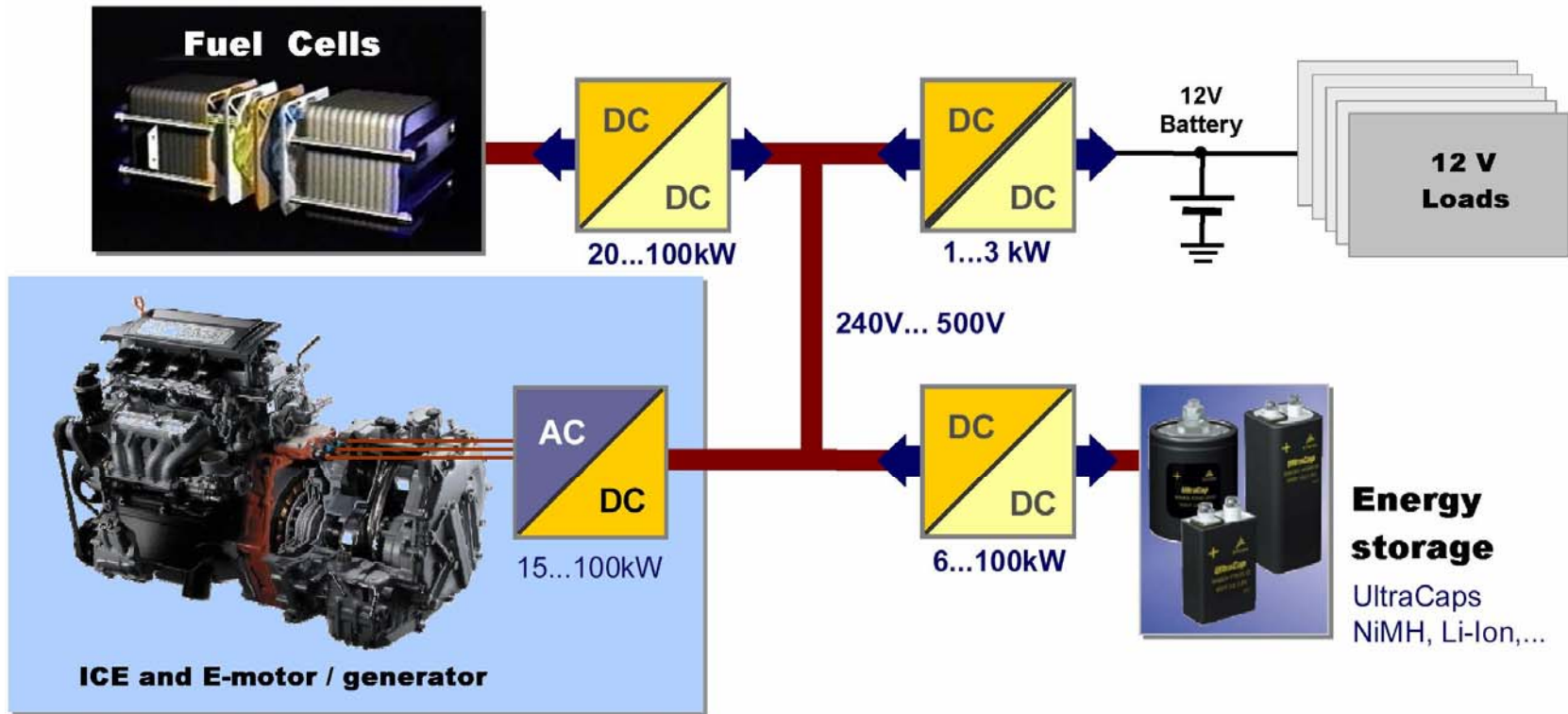
Co-ordinator: Siemens Corporate Technology

OEM	Supplier	Research Institutes
DaimlerChrysler (D)	Bosch (D)	Fraunhofer IISB (D)
Renault (F)	SiemensVDO (D)	INRETS (F)
Volkswagen (D)	Magna Steyr (A)	University of Technology Belfort-Montbéliard (F)
	Valeo (F)	Swiss Federal Institute of Technology Zurich (CH)
		Warsaw University of Technology (PL)

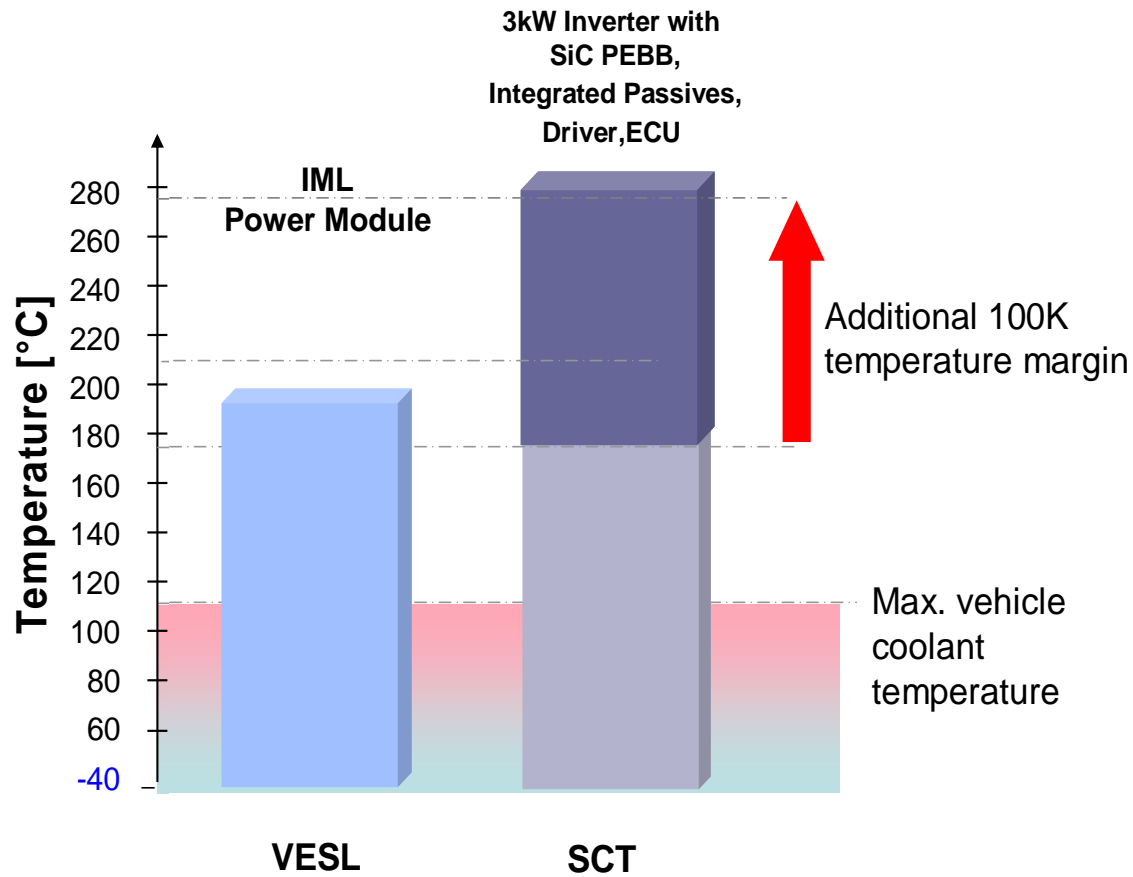
FC- and ICE- Hybrid Electric Vehicles: Classification



Block Diagram for FC- and ICE-HEV Powertrain



The two Concepts for New Power Electronics Modules in HOPE



Overview HOPE: Main Challenges

1. Performance

- High-temperature power electronics

2. Low Cost

- Use inserted molded leadframe concept without ceramic substrate insulation
- Introduce standardized power electronics building blocks

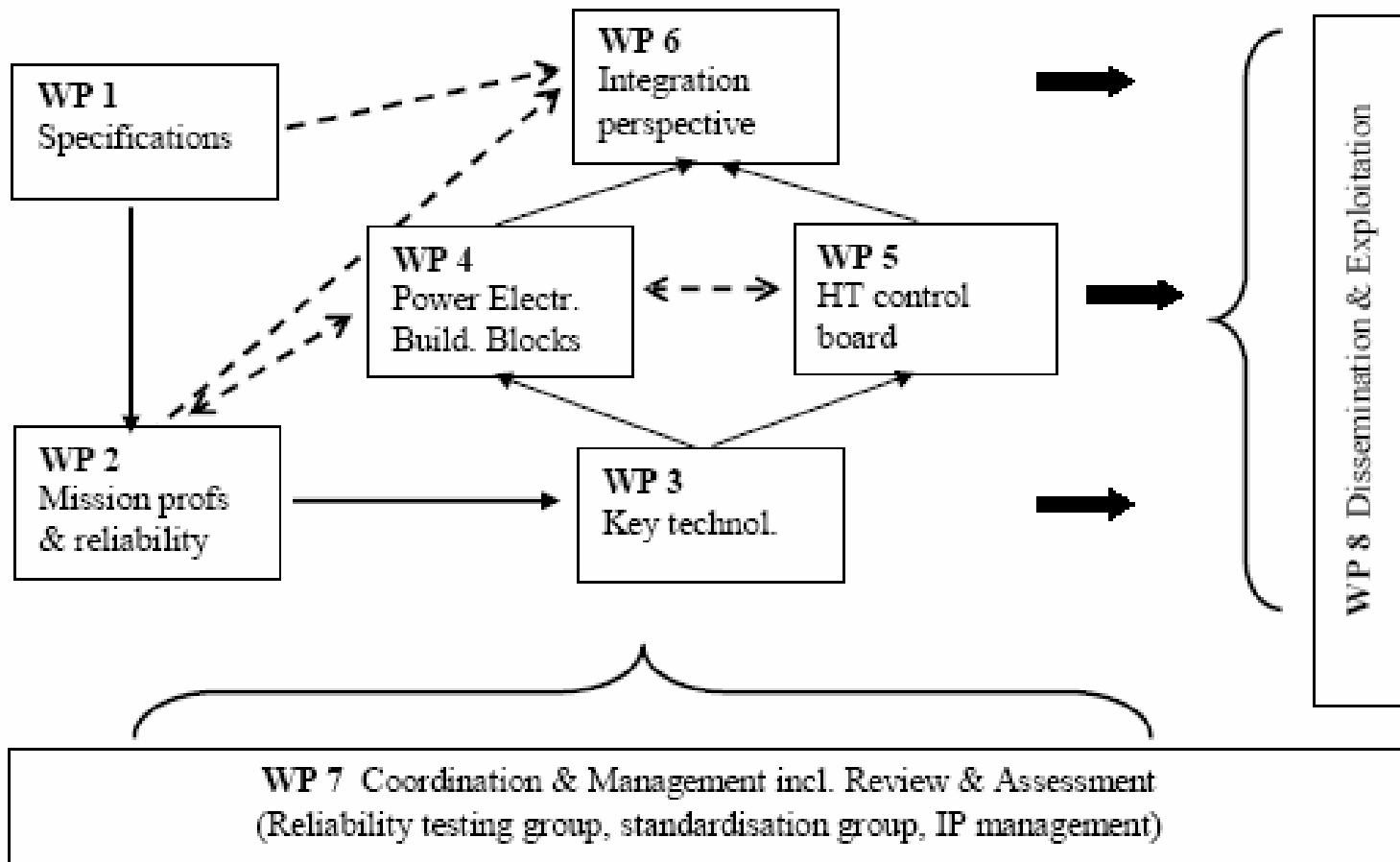
3. Reliability

- Failure rate increases with temperature

Comparison of the two NEW Concepts

	PMM (VESL)	SiC- PEBB (SCT)
New approach	Leadframe	SiC
Savings in contrast to state of the art	Ceramic-free insulator, integrated inter-connection with drive	No cooling circuit
Main research goals	Optimization of a set of materials (plastic, metals, solders) and thermal flow	Very high temperature operation
Main challenges	Reliability	Packaging, driver electronics, heat dissipation

HOPE: Interdependencies between the Workpackages



HOPE: List of Work Packages and Amount of Men Month

Work-package No ¹	Workpackage title	Lead contract. No ²	Person-months ³	Start month ⁴	End month ⁵	Deliverable No ⁶
1	Common specifications and standardisation evaluation	7	6	1	3	D1.1, D1.2
2	Mission profiles and reliability assessment	5	57	1	36	D2.1 – D2.7
3	Key technologies for high power density electronics	4	131	1	36	D3.1 – D3.8
4	Power electronic building blocks and inverters	1	44,5	6	36	D4.1 – D4.5
5	High temperature control board	9	15	1	36	D5.1, D5.2
6	Perspectives of inverter integration into powertrain	6	41	1	36	D6.1 – D6.4
7	Coordination and Management	1	8,3	1	36	D7.1 – D7.8
8	Dissemination and exploitation	1	10,25	1	36	D8.1 – D8.3
	TOTAL		313			

HOPE: Main Innovations / 1

1. Industrial standards for PEBB
 - Footprint
 - Height
 - Terminations
 - Interfaces to drivers and control electronics
 - Thermal interfaces
 - EMI properties
 - Materials (according to UL standards, etc.)

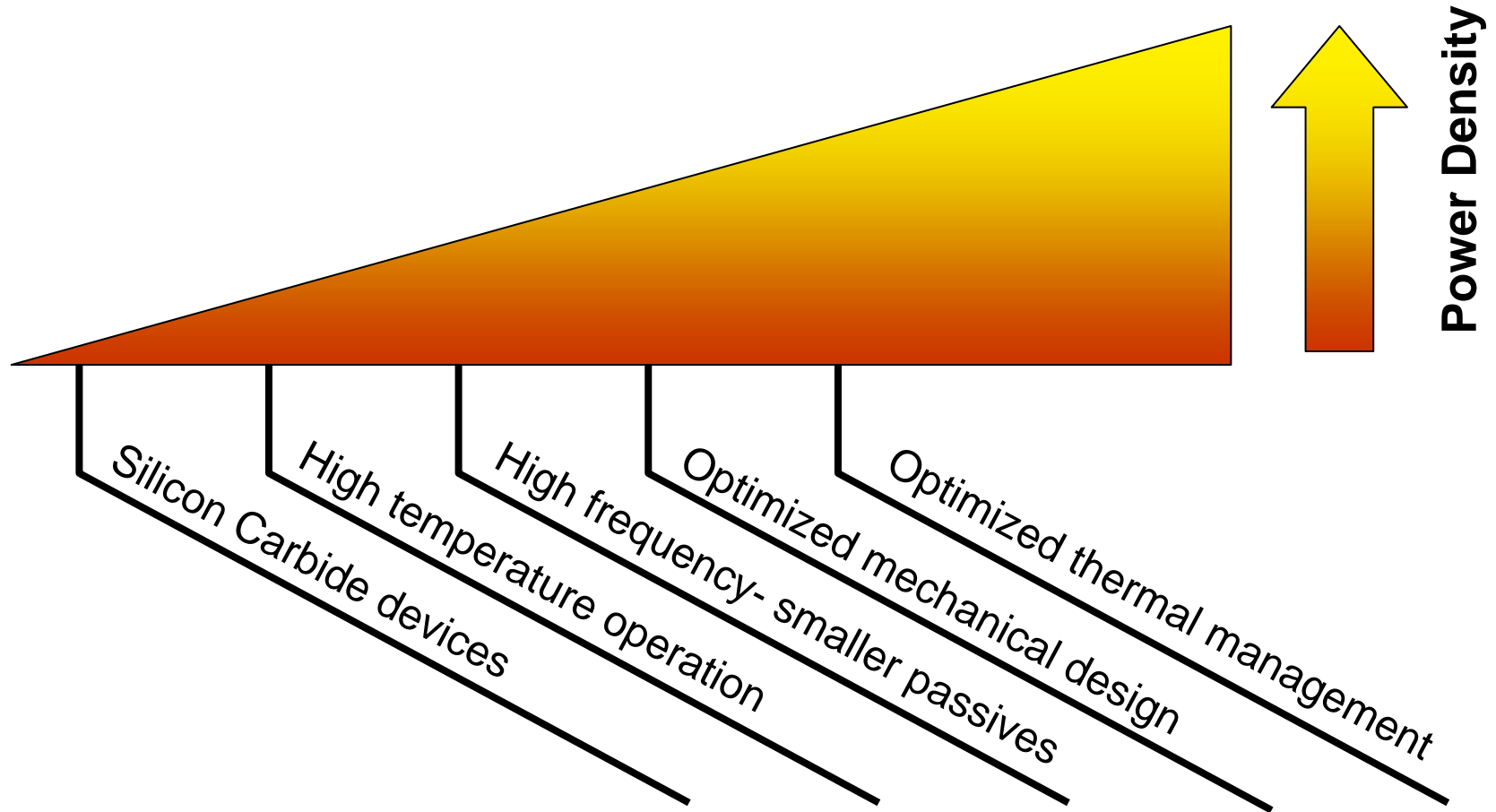
2. Subsystems level
 - topology for SiC-inverter
 - driver circuit for SiC
 - New cooling concepts e.g double-sided cooling
 - Mechatronic approach for inverter
 - Improved commutation cells for very fast switching

HOPE: Main Innovations / 2

3. Components and materials
 - RF and HT sensors
 - New materials,
 - New technologies for die attach and other joining e.g. nanoscale low temperature joining (LTJ)
 - New assembling technologies e.g. insert molded leadframe technology

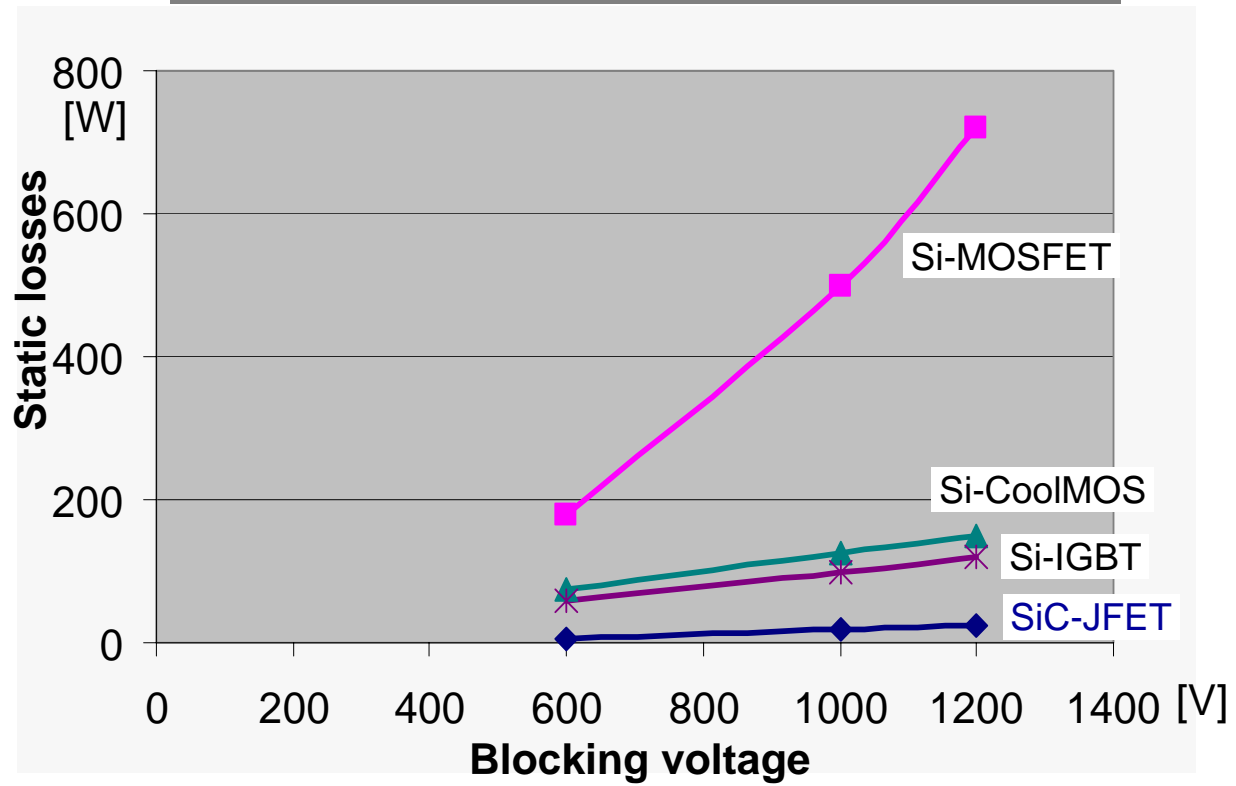
4. Test methodologies
 - Reliability tests
 - Mission profile tests
 - Lifetime prognosis

Expected Increase in Power Density by a Factor of 4 by using SiC JFETs





SiC-Transistors have in contrast to Si-Transistors less losses (1 cm², 50 A)

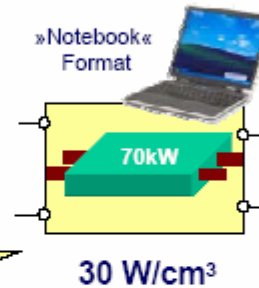




XXX

SiC power devices in electric vehicles

Lower losses for a given power rating
↓
Higher case temperatures possible



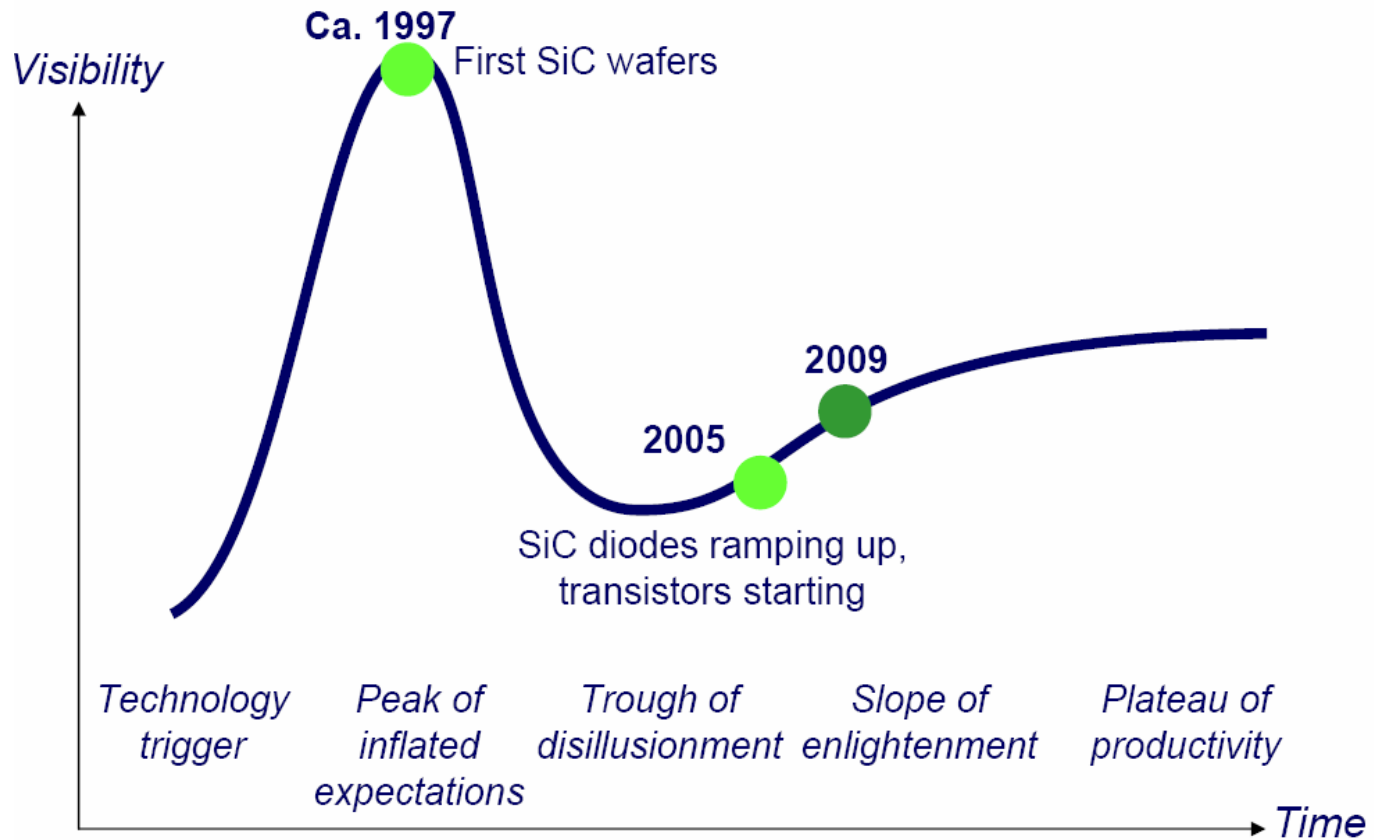
Higher operating temperatures possible
↓
Higher power density achievable

Robust components (e.g. radiation hard)
↓
Reliable operation also under harsh environmental conditions



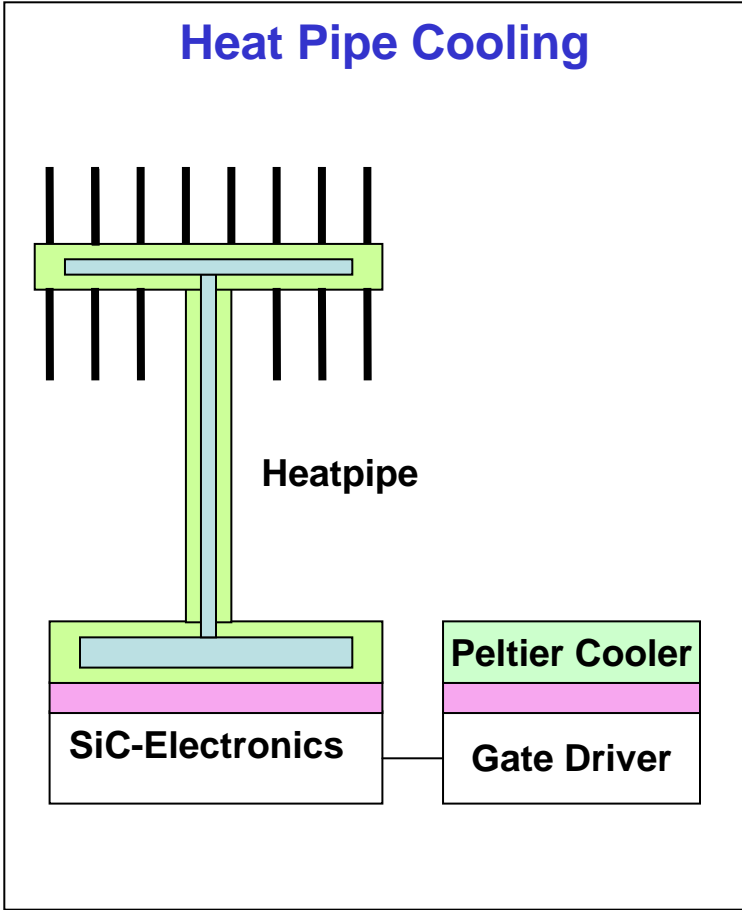
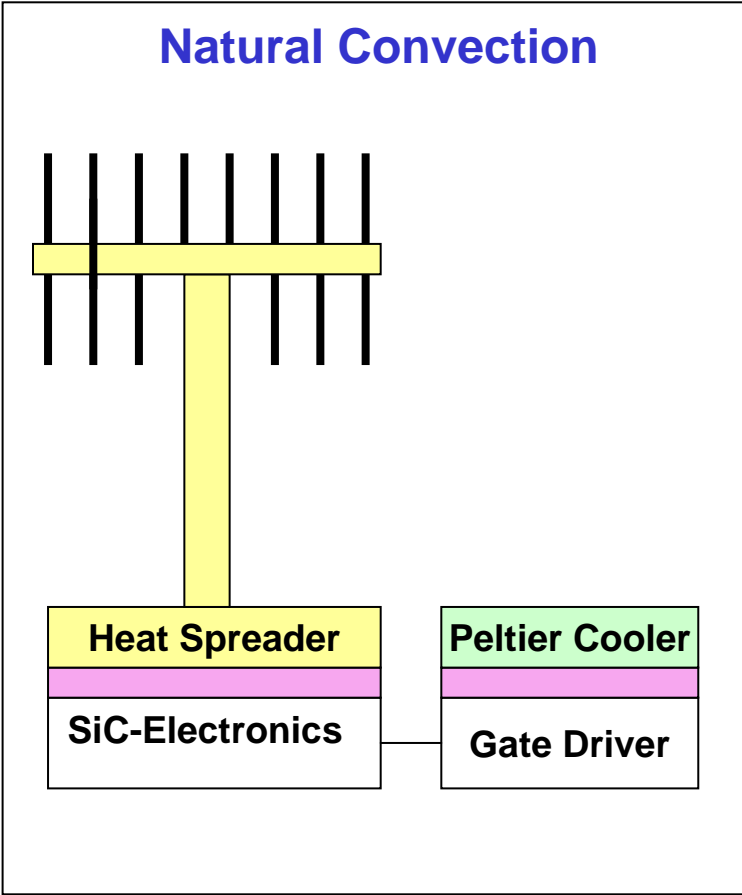
SICED
A Siemens Company

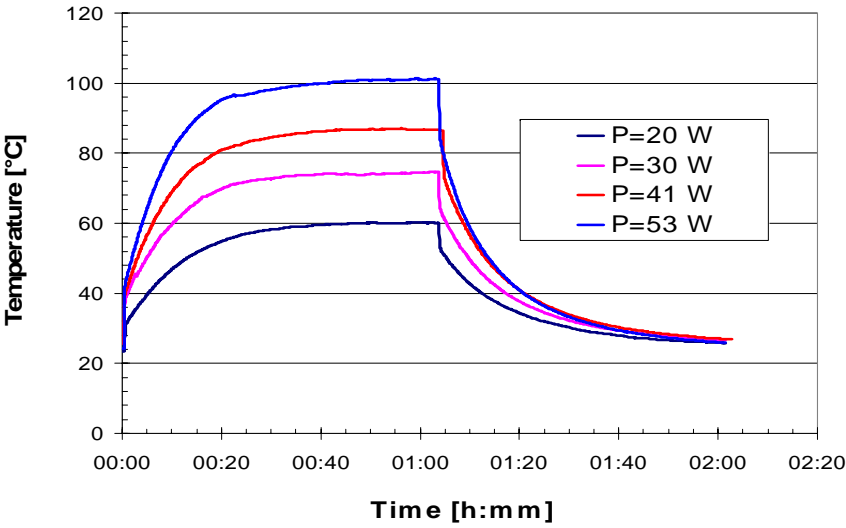
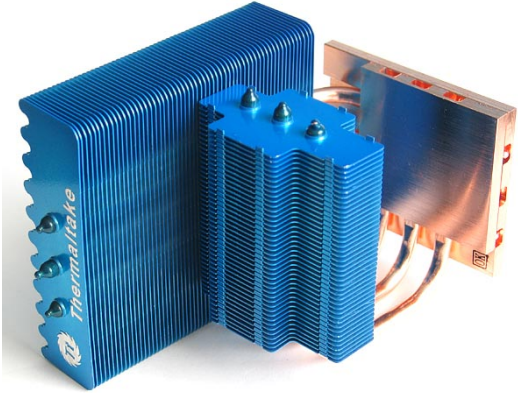
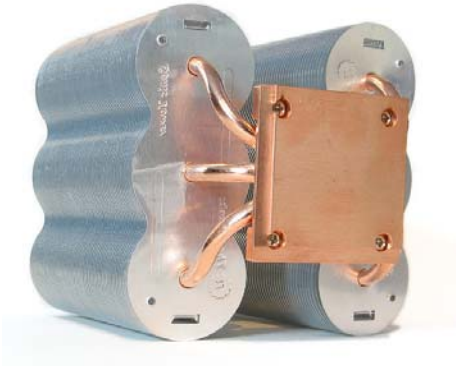
SiC-History



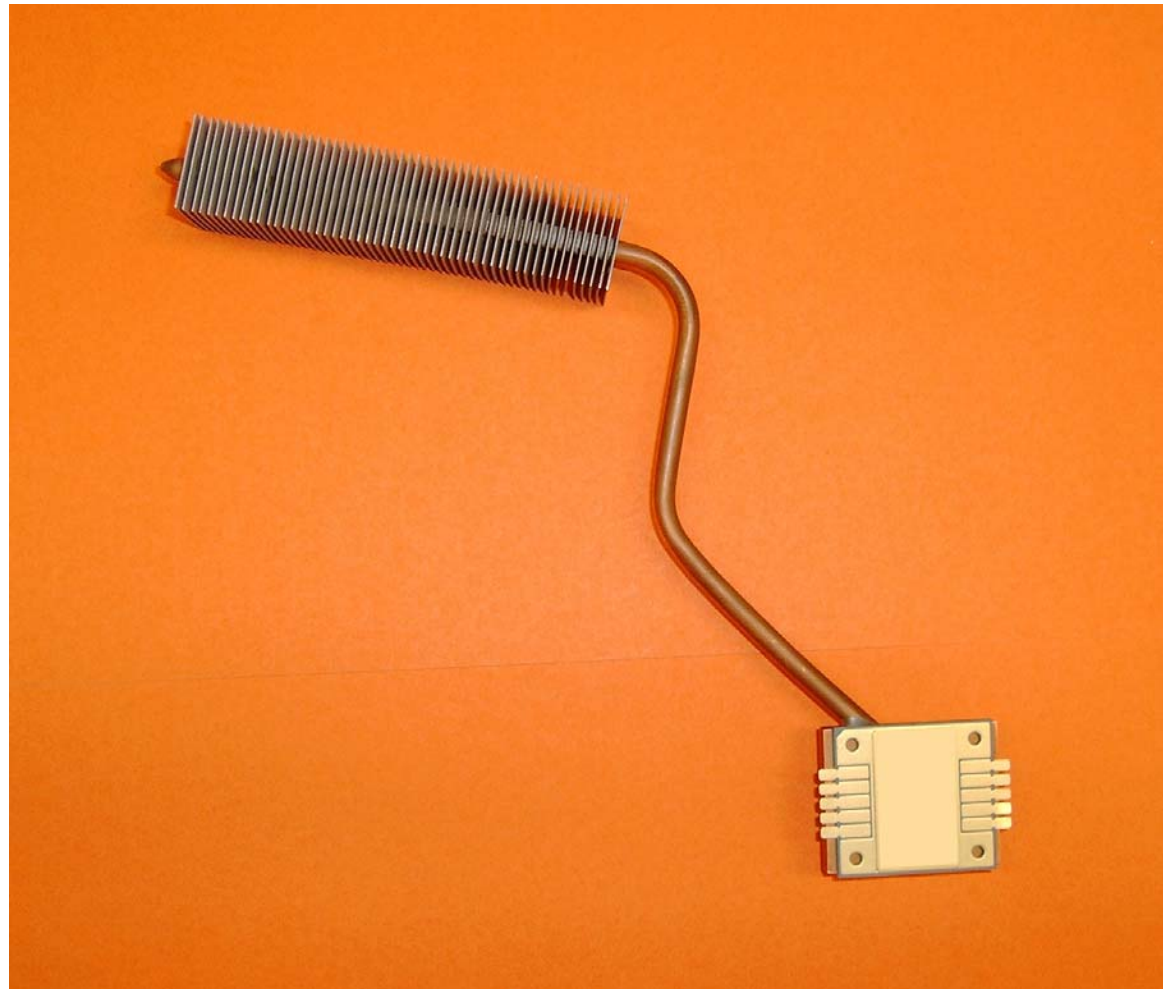
Source [3]

Passive Cooling Using the High Temperature Difference between SiC Junction and Ambient





Heatpipe



Status

- Deliverable D1.1 OEM specifications
- Deliverable D2.1 defines mission profiles
- Deliverable D3.1 defines PEBB / performance

- All devices and components are available and ready to build power electronics building blocks

Summary

HOPE wants to find out

- 1. Physical limits for high temp operation using SiC devices as an example
- 2. Find a cost effective solution using Valeos approach